Power management (dual transistors) **EMF8**

2SC5585 and DTC144EE are housed independently in a EMT6 package.

Application

Power management circuit

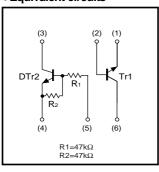
● Features

- 1) Power switching circuit in a single package.
- 2) Mounting cost and area can be cut in half.

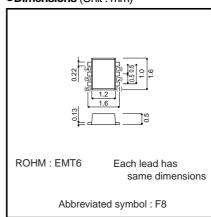
●Structure

Silicon epitaxial planar transistor

Equivalent circuits



●Dimensions (Unit:mm)



Package, marking, and packaging specifications

Туре	EMF8
Package	EMT6
Marking	F8
Code	T2R
Basic ordering unit (pieces)	8000

● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	15	V
Collector-emitter voltage	Vceo	12	V
Emitter-base voltage	Vево	6	V
Collector current	lc	500	mA
	ICP	1.0	A *1
Power dissipation	Pc	150(TOTAL)	mW *2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-55 to +150	°C

DTr2

Parameter	Symbol	Limits	Unit	
Supply voltage	Vcc	50	V	
Input voltage	Vin	-10 to +40	V	
Collector current	Ic	100	mA *1	
Output current	lo	30	mA	
Power dissipation	Pc	150(TOTAL)	mW *2	
Junction temperature	Tj	150	°C	
Range of storage temperature	Tstg	-55 to +150	°C	

●Electrical characteristics (Ta=25°C)

Tr1

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVceo	12	_	-	V	Ic=1mA
Collector-base breakdown voltage	ВУсво	15	_	_	V	Ic=10μA
Emitter-base breakdown voltage	ВVево	6	_	_	V	I _E =10μA
Collector cut-off current	Ісво	_	-	100	nA	Vcb=15V
Emitter cut-off current	ІЕВО	_	_	100	nA	V _{EB} =6V
Collector-emitter saturation voltage	VCE(sat)	_	100	250	mV	Ic=200mA, I _B =10mA
DC current gain	hfe	270	_	680	_	Vce=2V, Ic=10mA
Transition frequency	f⊤	_	320	_	MHz	Vce=2V, Ie=-10mA, f=100MHz
Collector output capacitance	Cob	_	7.5	_	pF	Vcb=10V, Ie=0mA, f=1MHz

DTr2

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input voltage	VI(off)	_	_	0.5	V	Vcc=5V, Io=100μA
	VI(on)	3.0	_	_	V	Vo=0.3V, Io=2mA
Output voltage	Vo(on)	_	100	300	mV	Vo=10mA, I:=0.5mA
Input current	lı	_	_	180	μΑ	Vi=5V
Output current	IO(off)	_	_	500	nA	Vcc=50V, Vi=0V
DC current gain	Gı	68	_	_	_	Vo=5V, Io=5mA
Transition frequency	f⊤	_	250	_	MHz	Vc=10V, I=-5mA, f=100MHz *
Input resistance	R ₁	32.9	47	61.1	kΩ	_
Resistance ratio	R2/R1	0.8	1.0	1.2	_	_

^{*}Characteristics of built-in transistor.



^{*1} Single pulse Pw=1ms
*2 120mW per element must not be exceeded.
Each terminal mounted on a recommended land.

^{*1} Characteristics of built-in transistor.
*2 120mW per element must not be exceeded.
Each terminal mounted on a recommended land.

•Electrical characteristic curves

Tr1

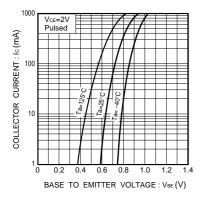


Fig.1 Grounded emitter propagation characteristics

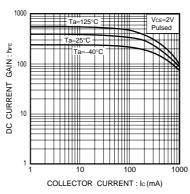


Fig.2 DC current gain vs. collector current

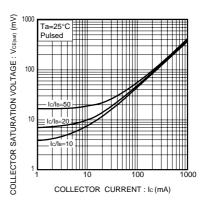


Fig.3 Collector-emitter saturation voltage vs. collector current (I)

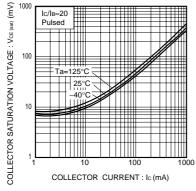


Fig.4 Collector-emitter saturation voltage vs. collector current (II)

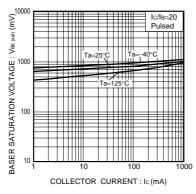


Fig.5 Base-emitter saturation voltage vs. collector current

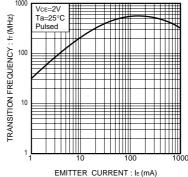


Fig.6 Gain bandwidth product vs. emitter current

Rev.B

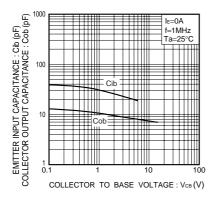


Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage



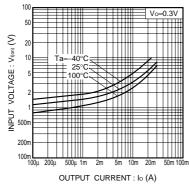


Fig.9 Input voltage vs. output current (ON characteristics)

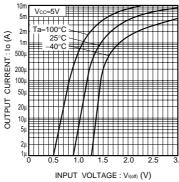


Fig.10 Output current vs. input voltage (OFF characteristics)

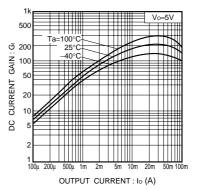


Fig.11 DC current gain vs. output

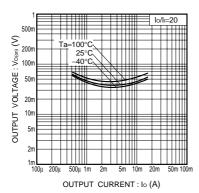


Fig.12 Output voltage vs. output current

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